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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/661,793	. 09/12/2003	Chi-An Kao	TS01-1037	8353
8933 DUANE MOR	7590 01/03/2008 RIS LLP		EXAMINER	
IP DEPARTMENT		NGUYEN, KHIEM D		
30 SOUTH 177 PHILADELPH	TH STREET IIA, PA 19103-4196		ART UNIT	PAPER NUMBER
	,		2823	
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Please find below and/or attached an Office communication concerning this application or proceeding.

The time period for reply, if any, is set in the attached communication.

	Application No.	Applicant(s)				
Office Action Summary	10/661,793	KAO ET AL.				
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The MAILING DATE of this communication app	Khiem D. Nguyen	2823				
Period for Reply	out on the outer shock with the	somespenaence aca. ecc				
A SHORTENED STATUTORY PERIOD FOR REPLY WHICHEVER IS LONGER, FROM THE MAILING DA  - Extensions of time may be available under the provisions of 37 CFR 1.13 after SIX (6) MONTHS from the mailing date of this communication.  - If NO period for reply is specified above, the maximum statutory period w  - Failure to reply within the set or extended period for reply will, by statute, Any reply received by the Office later than three months after the mailing earned patent term adjustment. See 37 CFR 1.704(b).	ATE OF THIS COMMUNICATION  B6(a). In no event, however, may a reply be tirgonial or the community of the com	N. nely filed the mailing date of this communication. ED (35 U.S.C. § 133).				
Status						
1) Responsive to communication(s) filed on 12 De	Responsive to communication(s) filed on <u>12 December 2007</u> .					
2a) ☐ This action is <b>FINAL</b> . 2b) ☑ This	,—					
	Since this application is in condition for allowance except for formal matters, prosecution as to the merits is					
closed in accordance with the practice under <i>Ex parte Quayle</i> , 1935 C.D. 11, 453 O.G. 213.						
Disposition of Claims						
<ul> <li>4)  Claim(s) 8-17 is/are pending in the application.</li> <li>4a) Of the above claim(s) is/are withdrawn from consideration.</li> <li>5)  Claim(s) 12-14 is/are allowed.</li> <li>6)  Claim(s) 8-11 and 15-17 is/are rejected.</li> <li>7)  Claim(s) is/are objected to.</li> <li>8)  Claim(s) are subject to restriction and/or election requirement.</li> </ul>						
Application Papers						
9) The specification is objected to by the Examiner 10) The drawing(s) filed on 12 September 2003 is/a Applicant may not request that any objection to the Replacement drawing sheet(s) including the correction 11) The oath or declaration is objected to by the Example 11.	re: a)⊠ accepted or b)⊡ object drawing(s) be held in abeyance. Se on is required if the drawing(s) is ob	e 37 CFR 1.85(a). ejected to. See 37 CFR 1.121(d).				
Priority under 35 U.S.C. § 119		•				
12) Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f).  a) All b) Some * c) None of:  1. Certified copies of the priority documents have been received.  2. Certified copies of the priority documents have been received in Application No.  3. Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)).  * See the attached detailed Office action for a list of the certified copies not received.						
Attachment(s)  1) Notice of References Cited (PTO-892)  2) Notice of Draftsperson's Patent Drawing Review (PTO-948)  3) Information Disclosure Statement(s) (PTO/SB/08)  Paper No(s)/Mail Date	4) Interview Summary Paper No(s)/Mail D 5) Notice of Informal F 6) Other:	ate				

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#### **DETAILED ACTION**

### Response to Applicants' Arguments and Amendment

1. Applicants' arguments, see page 3 in the response, filed on December 12<sup>th</sup>, 2007, with respect to the final rejection(s) of claim(s) 8-11 and 15-17 under 35 U.S.C. 102(e) have been fully considered and are persuasive. Therefore, the finality of that action has been withdrawn. However, upon further consideration, a new ground(s) of rejection is made in view of Sahin et al. (U.S. Pub. 2003/0220708).

# Claim Rejections - 35 USC § 102

2. The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

- (e) the invention was described in (1) an application for patent, published under section 122(b), by another filed in the United States before the invention by the applicant for patent or (2) a patent granted on an application for patent by another filed in the United States before the invention by the applicant for patent, except that an international application filed under the treaty defined in section 351(a) shall have the effects for purposes of this subsection of an application filed in the United States only if the international application designated the United States and was published under Article 21(2) of such treaty in the English language.
- 3. Claims 8-11 and 15-17 are rejected under 35 U.S.C. 102(e) as being anticipated by Sahin et al. (U.S. Patent 2003/0220708).

In re claim 8, <u>Sahin</u> discloses a system for creation of an opening of controllable format through a layer of insulation material, comprising:

means 102 for creating an opening 710a, 710b through a layer of etch resist material 708 provided over the surface of a layer of insulating material 704/706 having been deposited over the surface of a substrate 702 (see page 11, paragraphs [0150]-[0152] and FIGS. 7A-C);

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means for measuring an obtained critical dimension measurement of the opening **710a**, **710b** created through the layer of etch resist material **708** (see page 16, paragraph [0207] and step 803 in FIG. 8A(1));

means, including a feedback mechanism (see page 12, paragraph [0166]), for assuring that the obtained critical dimension measurement of the opening created through the layer of etch resist material 708 is within design specification (see page 16, paragraph [0210] and step 809 in FIG. 8A(1)), the feedback mechanism communicating with the means for creating an opening through a layer or etch resist material 708 to control the critical dimension (CD) measurement of the opening 710a, 710b (see page 6, paragraph [0211] and steps 807 and 810 of FIG. 8A(1)):

means for creating an opening 710a, 710b through the layer of insulation material 704/706, whereby a diameter of the opening 710a, 710b through the layer of insulation material 704/706 is dependent on a diameter of the opening 710a, 710b created through the layer of etch resist material 708 (see page 17, paragraphs [0214]-0215); and

means, including a feedback mechanism, for assuring that the opening **710a**, **710b** created through the layer of insulation material **704/706** is within design specification (see page 17, paragraphs [0216]-[0219]).

In re claim 9, as applied to claim 8 above, <u>Sahin</u> discloses all claimed limitations including the limitation wherein means, including a feedback mechanism (see page 12, paragraph [0166]), for assuring that an obtained critical dimension measurement of the opening 710a, 710b created through the layer of etch resist material 708 is within design specification comprising (see page 16, paragraph [0210] and step 809 in FIG. 8A(1)):

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means for linking to a software supervisory function, thereby including data transmission functions, means for linking to a software function equally being linked to a software supervisory function, thereby including data transmission functions; means for data manipulating capabilities, thereby including manipulating interdependent data; means for interfacing with semiconductor equipment, thereby including equipment functioning in a supporting role to the semiconductor equipment; and means for creating instructions for the semiconductor equipment, thereby including equipment functioning in a supporting role to the semiconductor equipment (see page 6, paragraph [0094]).

In re claim 10, as applied to claim 8 above, <u>Sahin</u> discloses all claimed limitations including the limitation wherein means for assuring that the opening **710a 710b** created through the layer of insulation material **704/706** is within design specification comprising: means for linking to a software supervisory function, thereby including data transmission functions, means for linking to a software function equally being linked to a software supervisory function, thereby including data transmission functions; means for data manipulating capabilities, thereby including manipulating interdependent data; means for interfacing with semiconductor equipment, thereby including equipment functioning in a supporting role to the semiconductor equipment; and means for creating instructions for the semiconductor equipment, thereby including equipment functioning in a supporting role to the semiconductor equipment (see page 6, paragraph [0094]).

In re claim 11, as applied to claim 8 above, <u>Sahin</u> discloses all claimed limitations including the limitation wherein the system further comprising means for creating an opening **710a**, **710b** having non-linear sidewalls through a layer of insulation material by

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applying a high-polymer based etch to the surface of the layer of insulation material 704/706 (see page 11, paragraph [0158]).

In re claim 15, <u>Sahin</u> discloses a system for creation of an opening of controllable format through a layer of insulation material, comprising:

means 102 for creating an opening 710a, 710b through a layer of etch resist material 708 provided over the surface of a layer of insulating material 704/706 having been deposited over the surface of a substrate 702 ((page 11, paragraphs [0150]-[0152] and FIGS. 7A-C);

means, including a feedback mechanism (see page 12, paragraph [0166]), for obtaining a critical dimension measurement of the opening created through the layer of etch resist material 708 assuring that the critical dimension measurement (CD) is within design specification (see page 16, paragraph [0210] and step 809 in FIG. 8A(1)), the feedback mechanism communicating with the means for creating an opening 710a, 710b through a layer of etch resist material 708 to control the critical dimension measurement (CD) of the opening 710a,710b (see page 6, paragraph [0211] and steps 807 and 810 of FIG. 8A(1));

means for creating an opening 710a, 710b having non-linear sidewalls through the layer of insulation material 704/076 by applying a high-polymer based etch to the surface of the layer of insulation material 704/706 (see paragraph [0158]), whereby a diameter of opening having non-linear sidewalls is dependent on a diameter of the opening created through the layer of etch resist material 708 (see page 17, paragraphs [0214]-0215); and

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means, including a feedback mechanism, for assuring that the opening **710a**, **710b** created through the layer of insulation material **704/706** is within design specification (see page 17, paragraphs [0216]-[0219]).

In re claim 16, <u>Sahin</u> discloses a system for creation of an opening of controllable format through a layer of insulation material, comprising:

means, including a feedback mechanism (see page 12, paragraph [0166]), for creating an opening **710a**, **710b** through a layer of etch resist material **708** provided over the surface of a layer of insulating material **704/706** having been deposited over the surface of a substrate **702**, such that the opening **710a**, **710b** has a critical dimension measurement (CD) that is within design specification (see page 16, paragraph [0210] and step 809 in FIG. 8A(1));

means for creating an opening **710a**, **710b** through the layer of insulation material **704/706**, whereby a diameter of layer of insulation material **704/706** is dependent on a diameter of the opening **710a**, **710b** created through the layer of etch resist material **708** (see page 17, paragraphs [0214]-0215); and

means, including a feedback mechanism, for assuring that the opening created through the layer of insulation material is within design specification (see page 17, paragraphs [0216]-[0219]).

In re claim 17, as applied to claim 16 above, <u>Sahin</u> discloses all claimed limitations including the limitation wherein the means, including a feedback mechanism, for creating an opening **710a**, **710b** (see page 12, paragraph [0166]) include means for

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making corrections to an original critical dimension measurement (CD) that is not within design specification (see page 17, paragraphs [0214]-[0215]).

## Allowable Subject Matter

4. Claims 12-14 were previously allowed over prior art of record as indicated in the Office Paper mailed on March 08<sup>th</sup>, 2005.

## Response to Applicants' Amendment and Arguments

5. Applicants' arguments with respect to claims 8-11 and 15-17 have been considered but are most in view of the new ground(s) of rejection.

#### Correspondence

6. Any inquiry concerning this communication or earlier communications from the examiner should be directed to Khiem D. Nguyen whose telephone number is (571) 272-1865. The examiner can normally be reached on Monday-Friday (8:30 AM - 5:30 PM).

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Matthew S. Smith can be reached on (571) 272-1907. The fax phone number for the organization where this application or proceeding is assigned is 571-273-8300.

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Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free). If you would like assistance from a USPTO Customer Service Representative or access to the automated information system, call 800-786-9199 (IN USA OR CANADA) or 571-272-1000.

K.N.

December 28, 2007

BROOK KEBEDE PRIMARY EXAMINED

Brook Kehede